

isc Silicon NPN Power Transistor

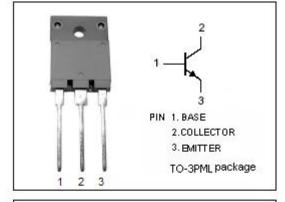
2SC4585

DESCRIPTION

- · Collector-Emitter Sustaining Voltage-
 - : V_{CEO(SUS)}= 800V(Min)
- · Fast Switching speed
- 100% avalanche tested
- Minimum Lot-to-Lot variations for robust device performance and reliable operation

APPLICATIONS

Designed for power switching applications.

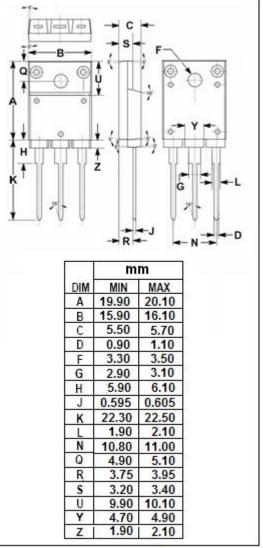


ABSOLUTE MAXIMUM RATINGS(Ta=25℃)

SYMBOL	PARAMETER	VALUE	UNIT
V _{CBO}	Collector-Base Voltage	1200	V
V _{CEO}	Collector-Emitter Voltage	800	V
V _{EBO}	Emitter-Base Voltage	7	V
Ic	Collector Current-Continuous	10	А
I _{CM}	Collector Current-Peak	20	А
I _B	Base Current-Continuous	4	А
I _{BM}	Base Current-Peak	8	А
P _T	Total Power Dissipation @ Tc=25℃	85	W
TJ	Junction Temperature	150	$^{\circ}$
T _{stg}	Storage Temperature Range	-55~150	$^{\circ}$

THERMAL CHARACTERISTICS

SYMBOL	PARAMETER	MAX	UNIT
Rth j-c	Thermal Resistance,Junction to Case	1.47	°C/W





ISC Silicon NPN Power Transistor

2SC4585

ELECTRICAL CHARACTERISTICS

Tc=25℃ unless otherwise specified

SYMBOL	PARAMETER	CONDITIONS	MIN	TYP.	MAX	UNIT		
V _{CEO(SUS)}	Collector-Emitter Sustaining Voltage	I _C = 0.2A; I _B = 0	800			V		
V _{CE(sat)}	Collector-Emitter Saturation Voltage	I _C = 5A; I _B = 1A			1.0	V		
V _{BE(sat)}	Base-Emitter Saturation Voltage	I _C = 5A; I _B = 1A			1.5	V		
I _{CBO}	Collector Cutoff Current	At rated Voltage			100	μА		
I _{CEO}	Collector Cutoff Current	At rated Voltage			100	μА		
I _{EBO}	Emitter Cutoff Current	At rated Voltage			100	μА		
h _{FE-1}	DC Current Gain	Ic= 5A; Vc== 5V	8					
h _{FE-2}	DC Current Gain	I _C = 1mA; V _{CE} = 5V	7					
f _T	Current-Gain—Bandwidth Product	I _C = 1A; V _{CE} = 10V		8		MHz		
Switching times								
ton	Turn-on Time				0.5	μs		
t _{stg}	Storage Time	I _C = 5A, I _{B1} = 1A; I _{B2} = -2A; R _L = 50 Ω; V _{BB2} = 4V			3.5	μs		
t _f	Fall Time				0.3	μs		

NOTICE:

ISC reserves the rights to make changes of the content herein the datasheet at any time without notification. The information contained herein is presented only as a guide for the applications of our products.

ISC products are intended for usage in general electronic equipment. The products are not designed for use in equipment which require specialized quality and/or reliability, or in equipment which could have applications in hazardous environments, aerospace industry, or medical field. Please contact us if you intend our products to be used in these special applications.

ISC makes no warranty or guarantee regarding the suitability of its products for any particular purpose, nor does ISC assume any liability arising from the application or use of any products, and specifically disclaims any and all liability, including without limitation special, consequential or incidental damages.

isc Website: www.iscsemi.cn